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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Alessia Pavan, et al.

Title: **NON-VOLATILE MEMORY CELL COMPRISING
DIELECTRIC LAYERS HAVING A LOW DIELECTRIC CONSTANT
AND CORRESPONDING MANUFACTURING PROCESS**

Application No.: 10/749,130

Filing Date: December 30, 2003

Group Art Unit: 2818

Attorney Docket No.: 2110-099-03

CERTIFICATE OF MAILING OR TRANSMISSION

I hereby certify that this correspondence is being deposited in the United States Postal Service as First Class mail in an envelope addressed to: MS Amendments, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 15TH day of May, 2006.

Signature

AMENDMENT AND RESPONSE UNDER 37 CFR §1.111

TO THE COMMISSIONER FOR PATENTS

Reconsideration of the above-referenced patent application in view of the following amendments and remarks is requested. Please amend the application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 7 of this paper.